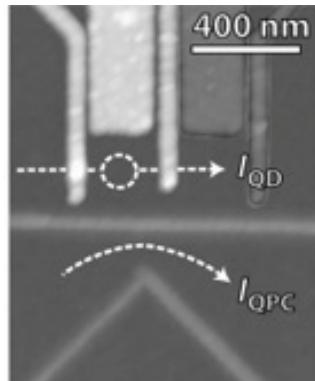


Time-dependent single-electron transport: irreversibility and out-of-equilibrium



Klaus Ensslin

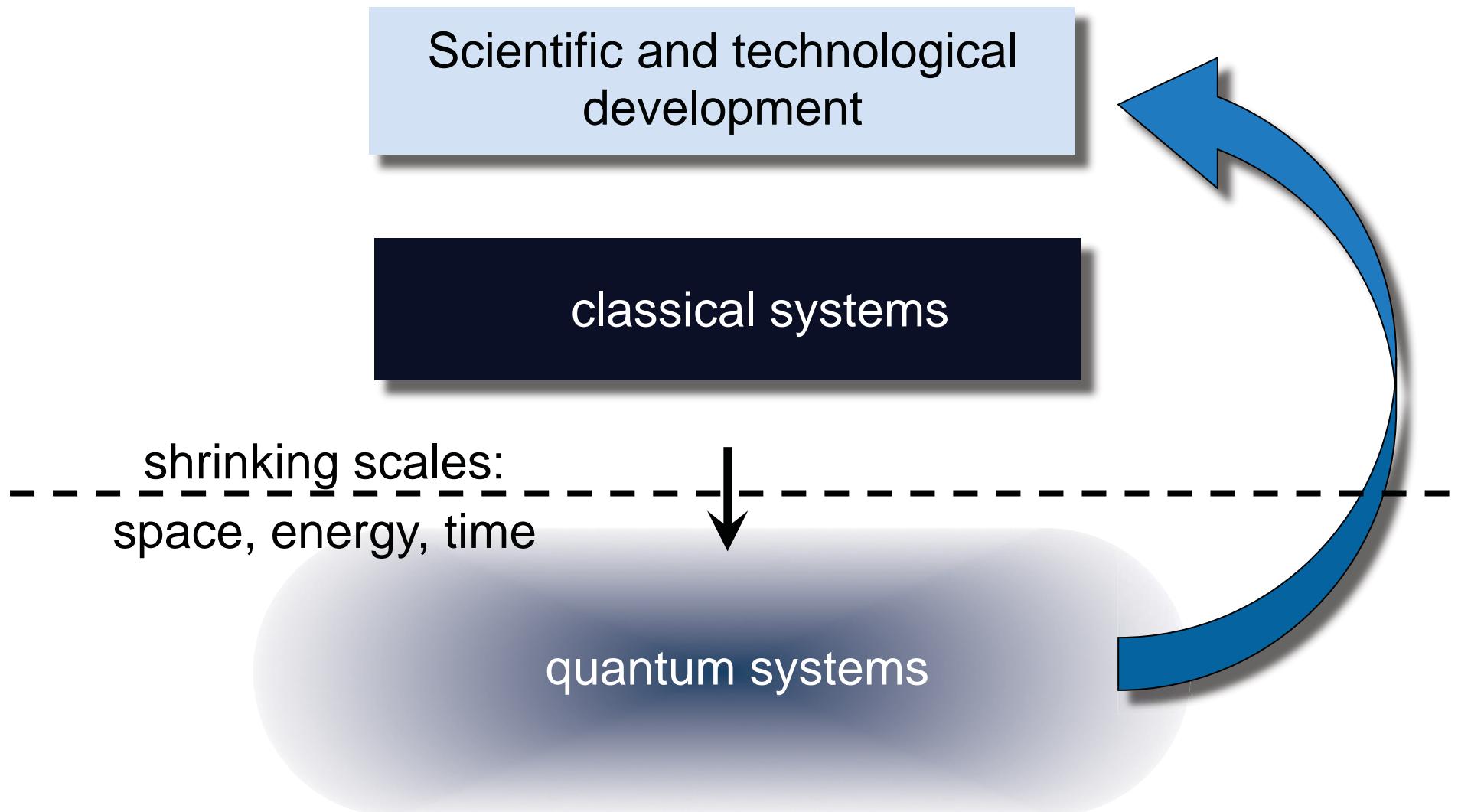


Solid State Physics

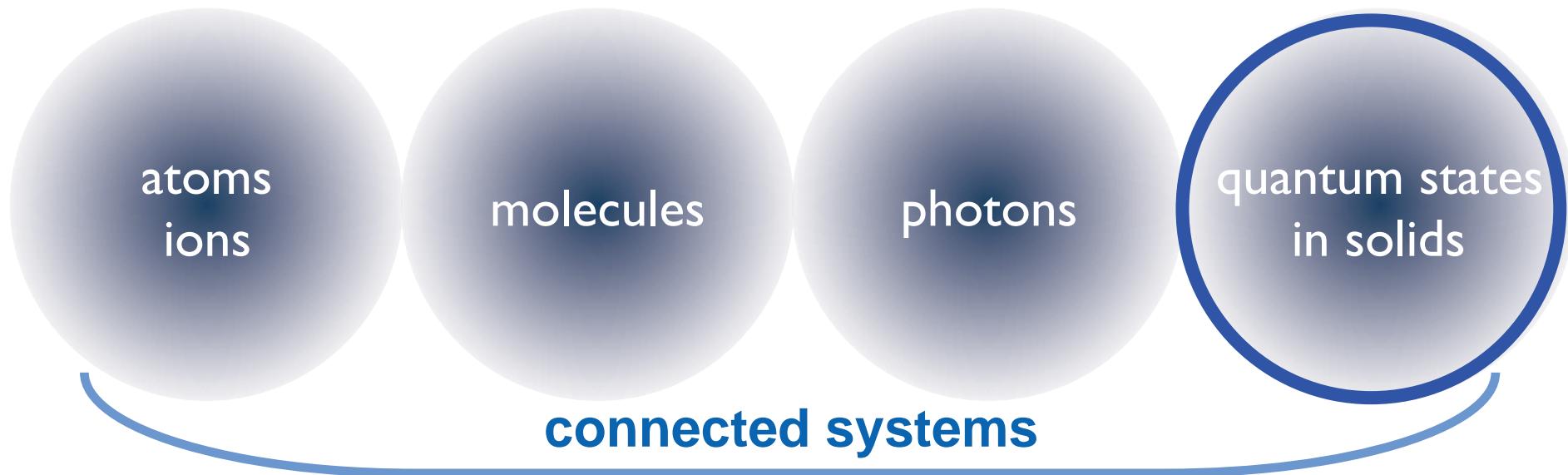
Zürich

1. quantum dots
2. electron counting
3. counting and irreversibility
4. Microwave resonator coupled to quantum dots

Quantum Technology

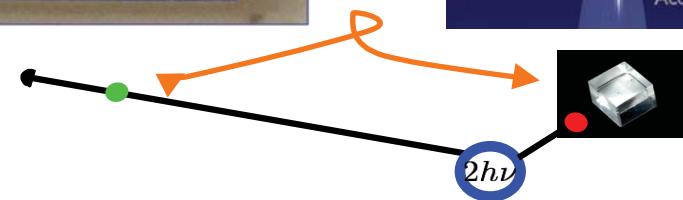
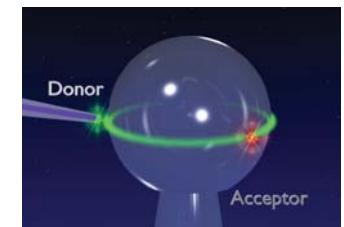
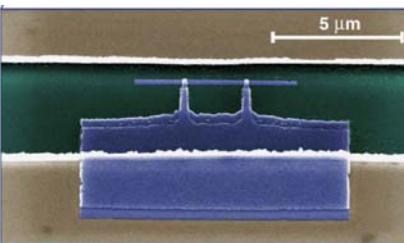
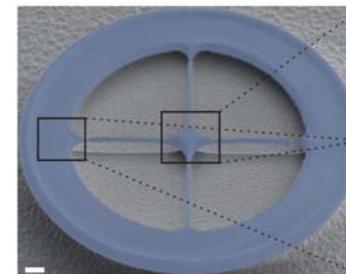
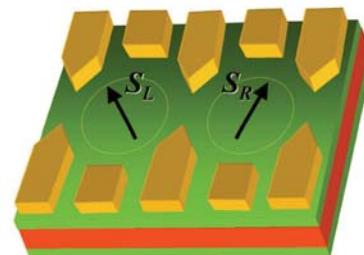
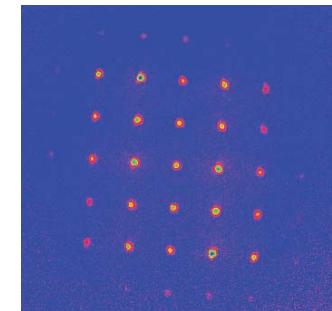
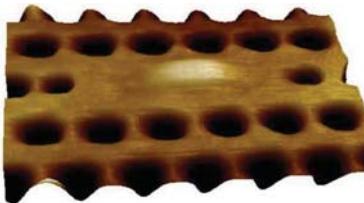
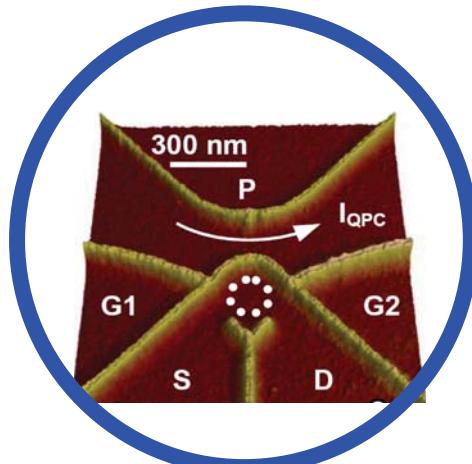


Engineering of Quantum Systems



1. quantum computing, quantum simulation, quantum cryptography
2. matter wave sensors, optical frequency synthesizer
3. super-chemistry and quantum materials
4. interference-based devices

Quantum Science and Technology in Switzerland



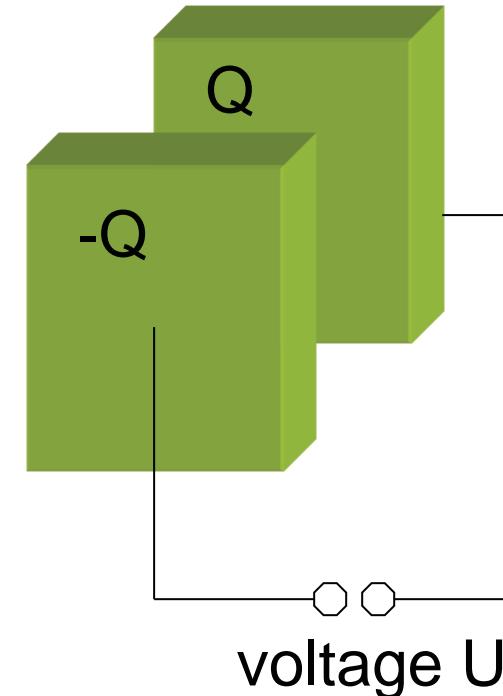
Quantized Charge

Capacitance of a capacitor:

$$C = \frac{|Q|}{U} = \frac{\text{charge}}{\text{voltage}}$$

Energy to charge the capacitor:

$$E = \int_0^Q U dQ = \int_0^Q \frac{Q}{C} dQ = \frac{Q^2}{2C}$$



Energy to put one electron ($Q=e$) on a capacitor with $C = 1 \text{ nF}$

$$E = \frac{(1.6 \cdot 10^{-19} \text{ As})^2}{2 \cdot 10^{-9} \text{ F}} = 1.3 \cdot 10^{-29} \text{ Joule} = 8 \cdot 10^{-9} \text{ eV}$$

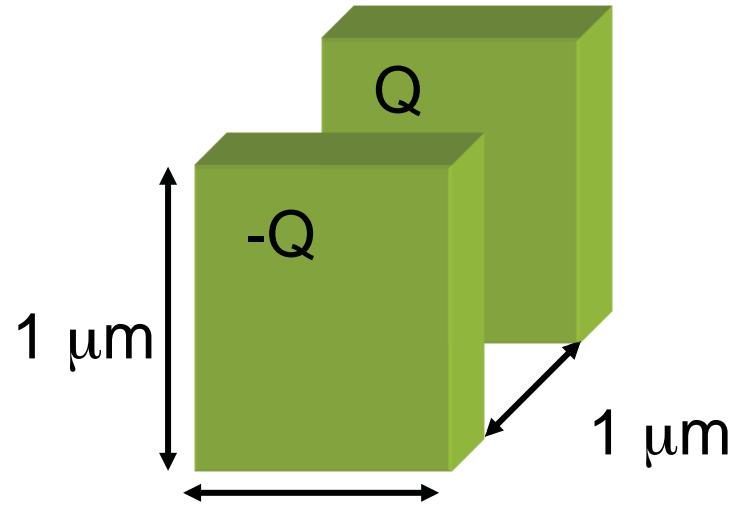
Equivalent to temperature $T = 0.1 \text{ mK}$

Size of a Capacitor

Capacitance

$$C = \epsilon \epsilon_0 \frac{\text{area}}{\text{separation}} = \\ = \epsilon \epsilon_0 \frac{(1 \mu\text{m})^2}{1 \mu\text{m}} = 10^{-16} \text{ F}$$

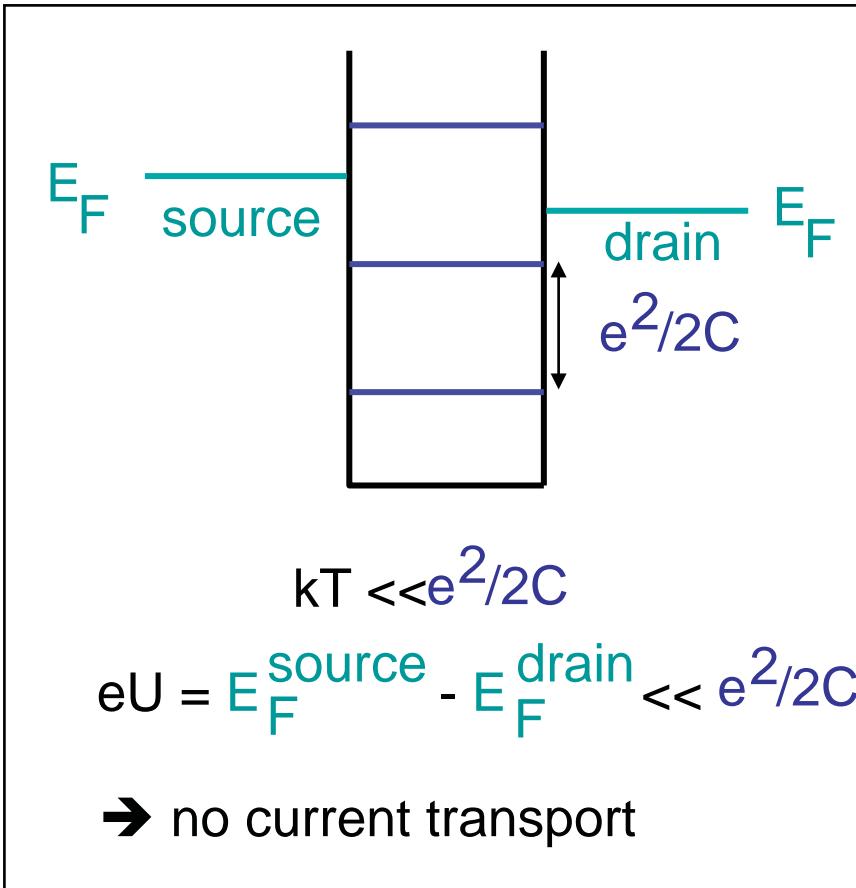
Equivalent to temperature $T = 7 \text{ K}$



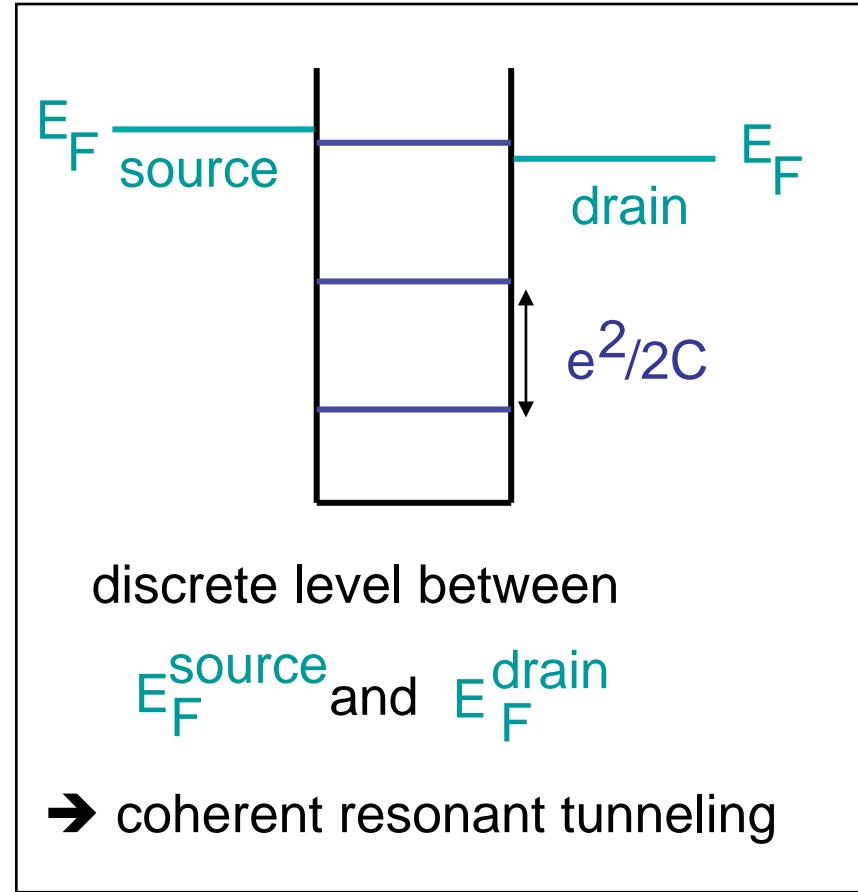
-> use nanotechnology to make a small capacitor

decoupled from its environment

Coulomb Blockade



disk: r $C = 8\epsilon\epsilon_0 r$

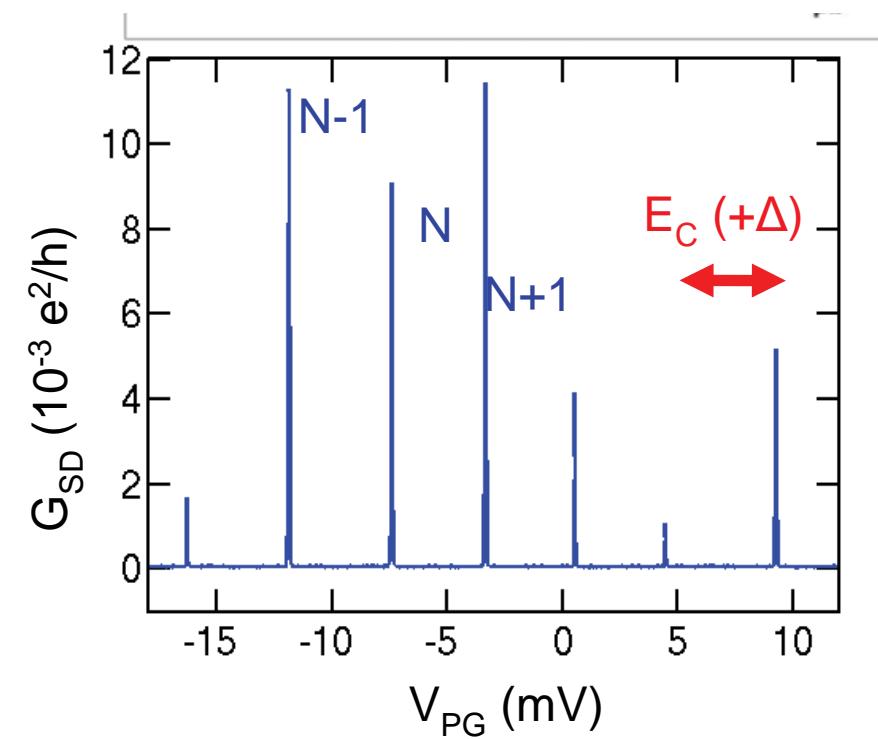
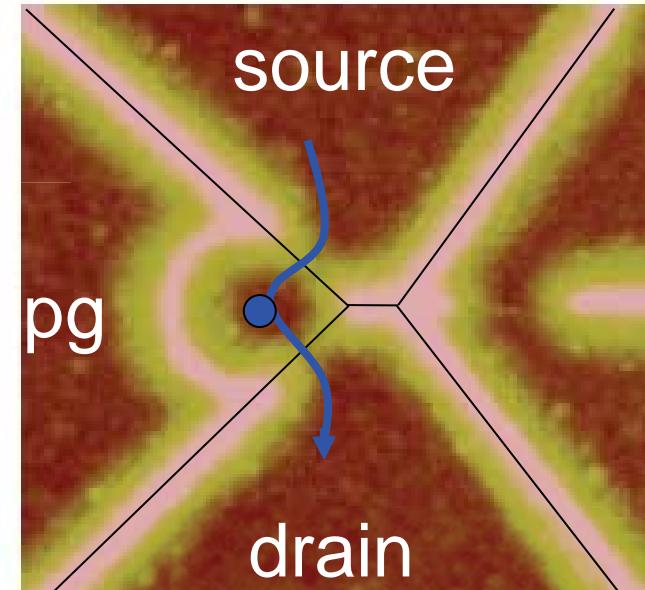
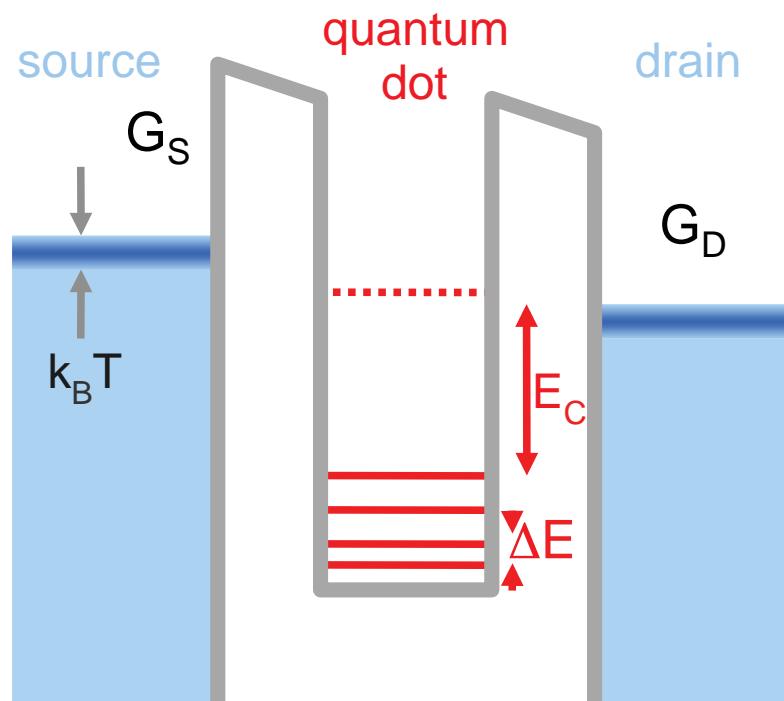


$$r = 100 \text{ nm}$$

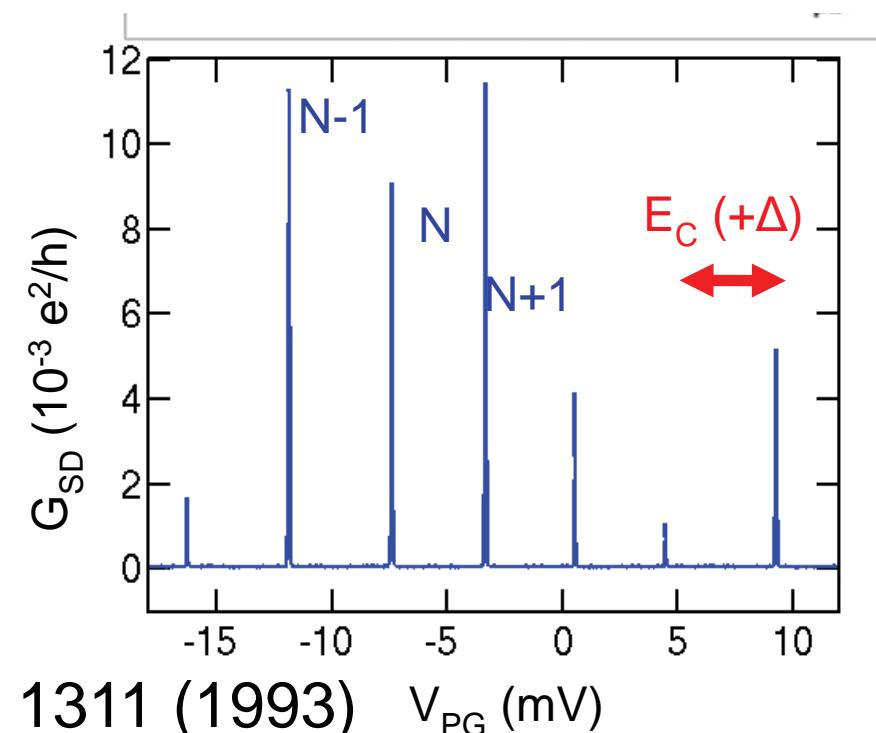
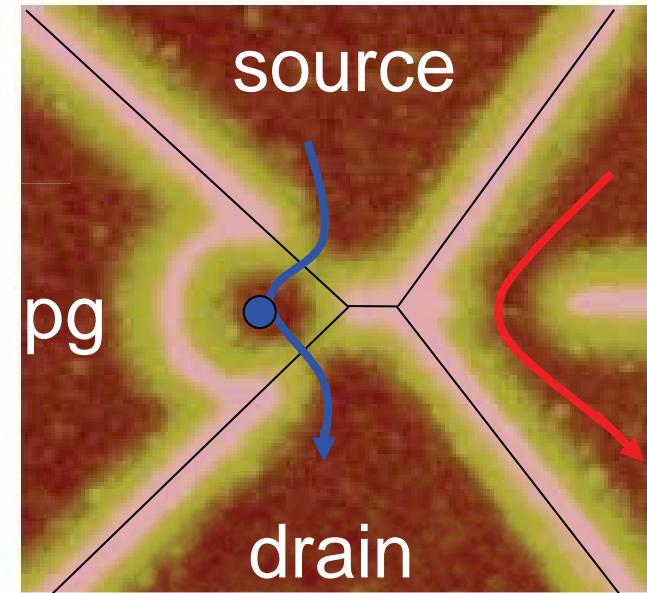
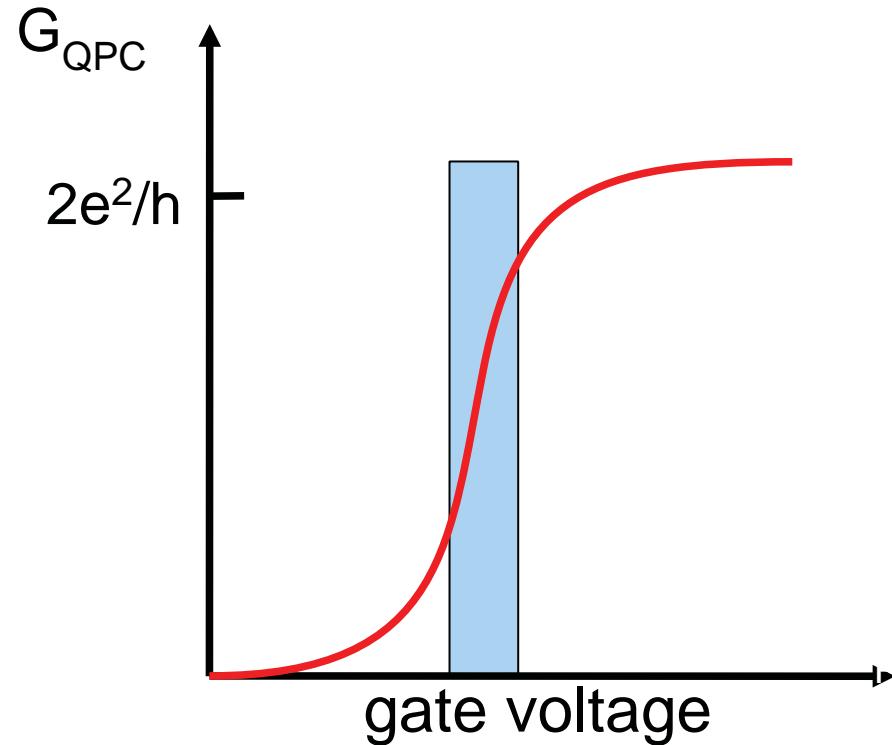
$$\rightarrow C = 84 \text{ aF}$$

$$\rightarrow e^2/2C = 900 \mu\text{eV} \approx 11 \text{ K}$$

Spectroscopy of electronic states

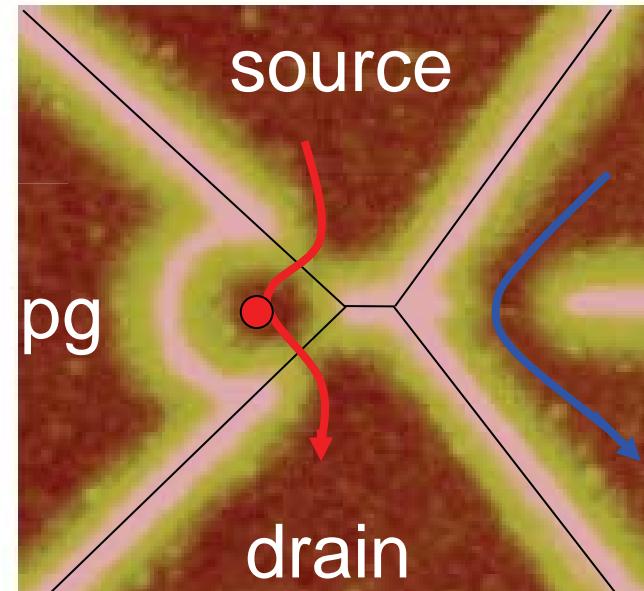
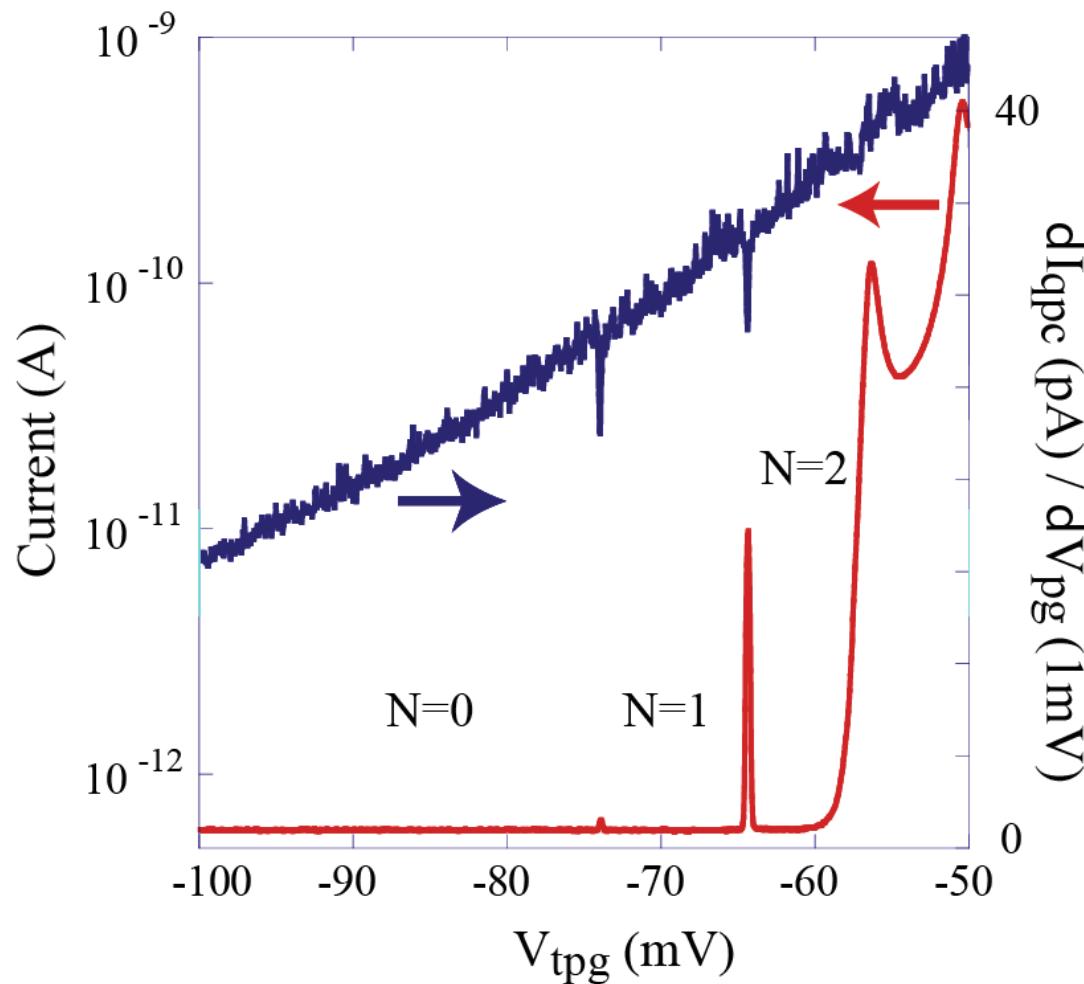


Quantum point contact as a charge detector



M. Field et al., Phys. Rev. Lett. 70, 1311 (1993)

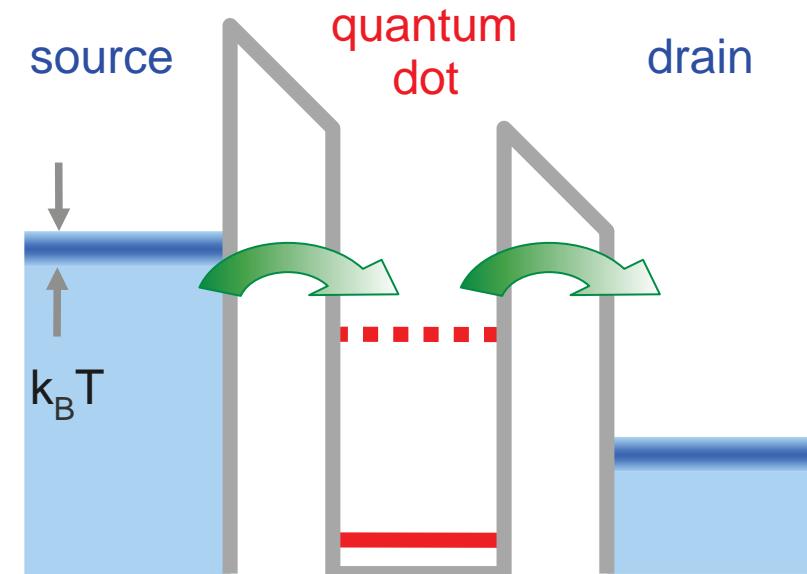
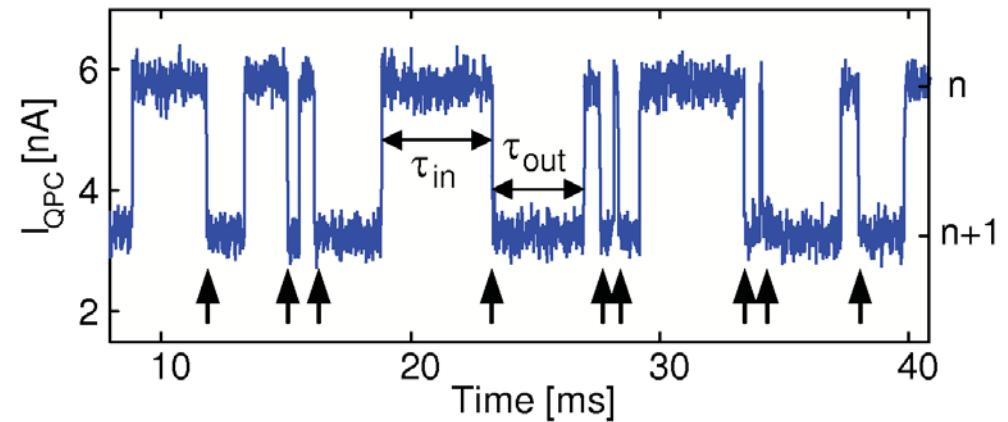
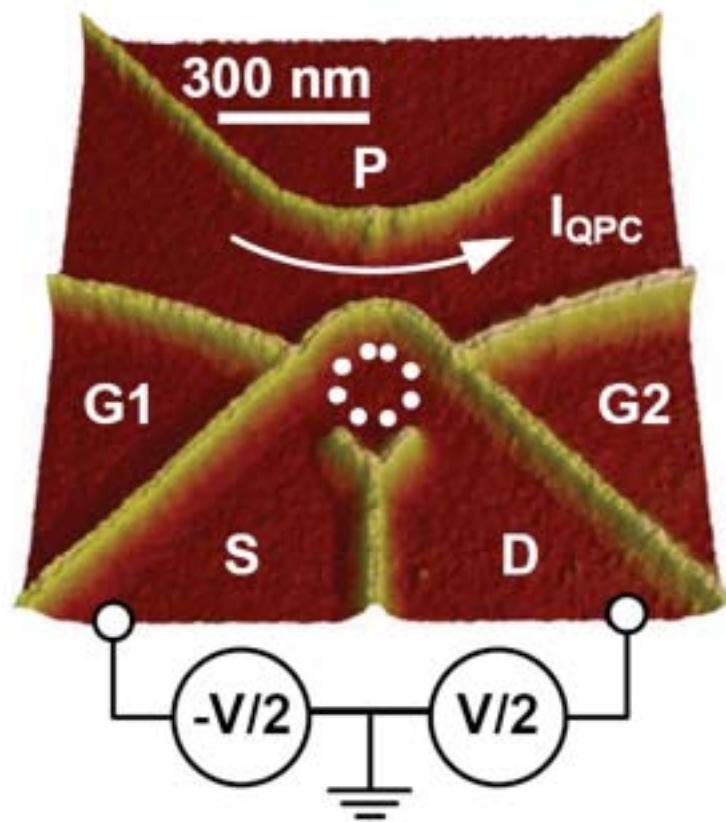
A few electron quantum dot



M. Sigrist

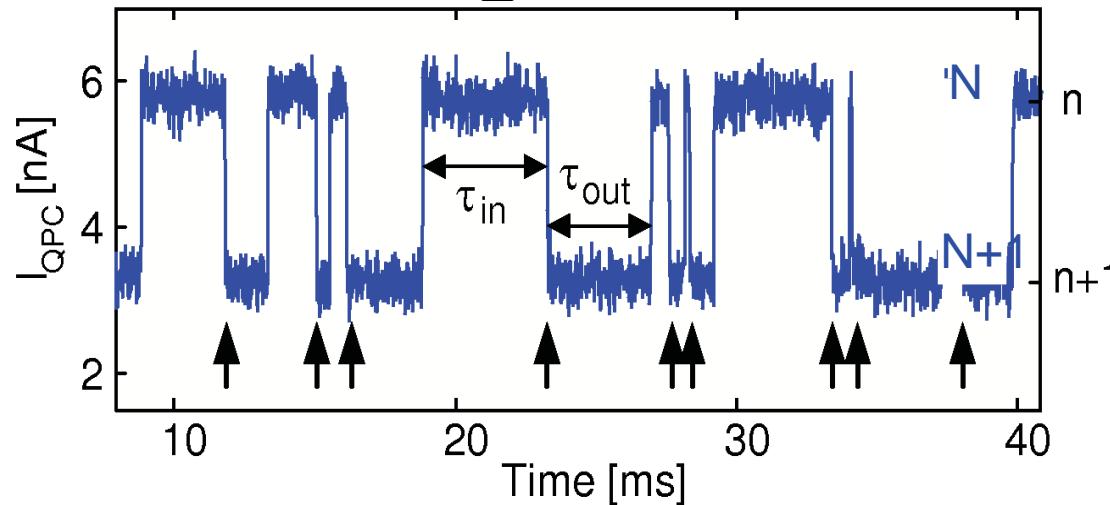
Ciorga et al.,
PRB 61, R16315 (2000)
Elzerman et al.
PRB 67, 161308 (2003)

Time-resolved detection of single electron transport



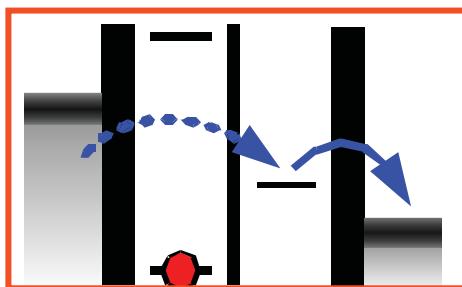
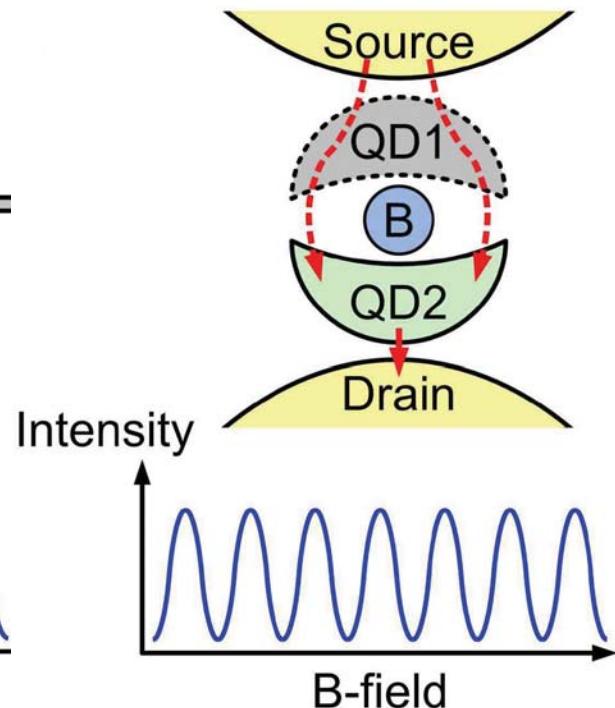
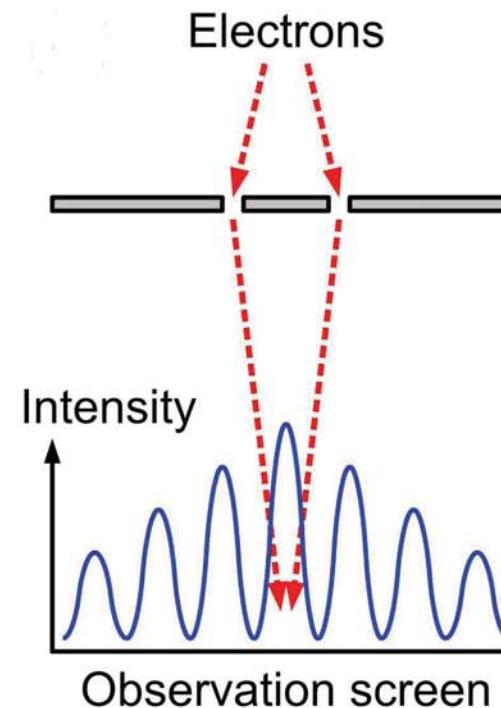
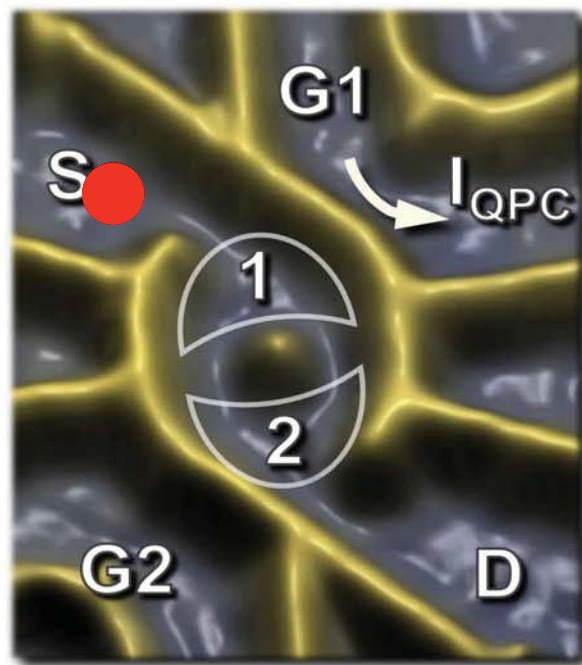
Schleser et al., APL 85, 2005 (2004)
Vandersypen et al., APL 85, 4394 (2004)

Measuring the current by counting electrons

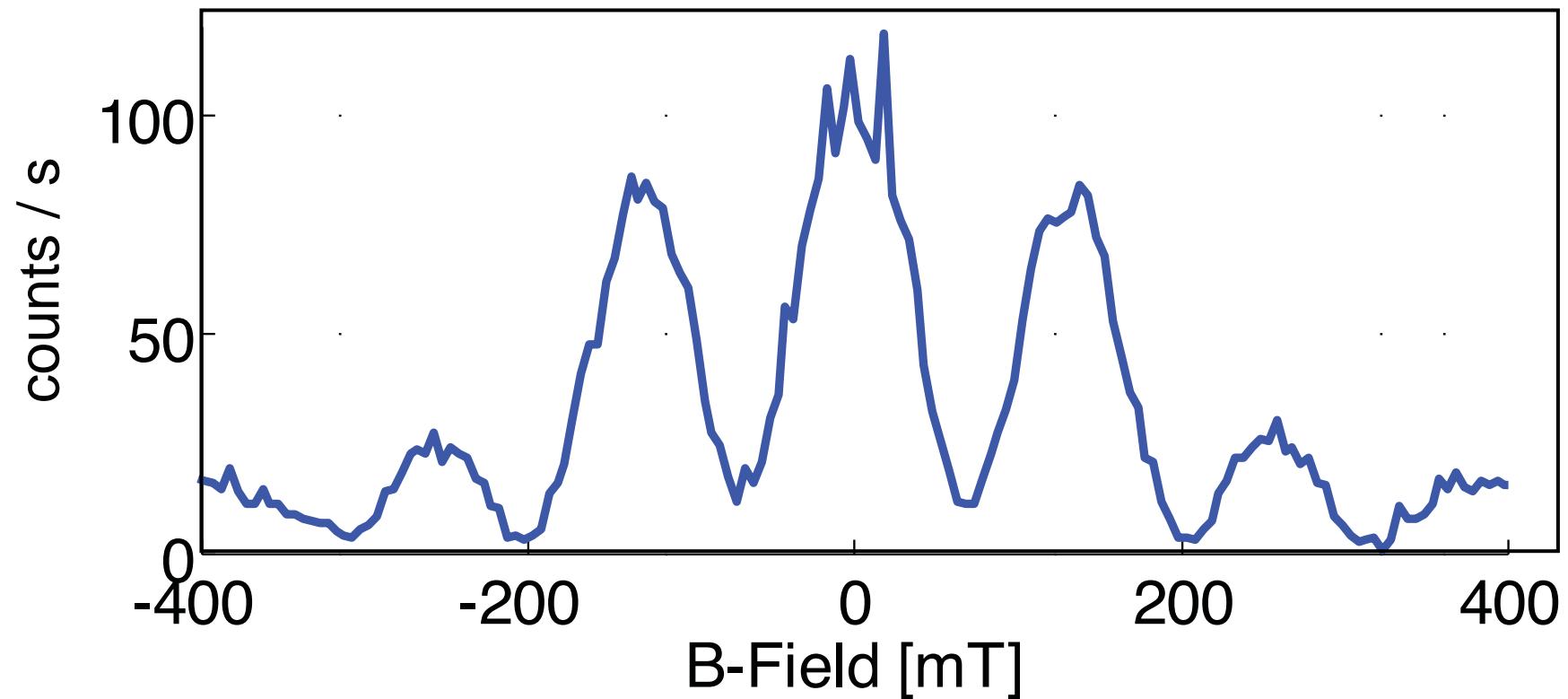


- Count number n of electrons entering the dot within a time t_0 : $I = e\langle n \rangle/t_0$
- Max. current = few fA (bandwidth = 30 kHz)
- BUT no absolute limitation for low current and noise measurements
-> here: $I \approx \text{few aA}$, $S_I \approx 10^{-35} \text{ A}^2/\text{Hz}$

Double slit experiment <-> Aharonov Bohm



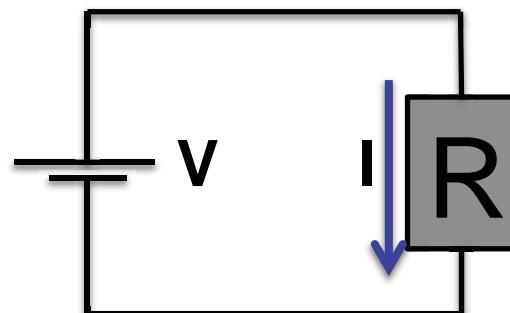
Aharonov-Bohm oscillations



huge visibility! >90%, stable in temperature up to 400 mK
little decoherence - \rightarrow cotunneling is much faster than
decoherence time

Gustavsson et al. Nanoletters 8, 2547 (2008)

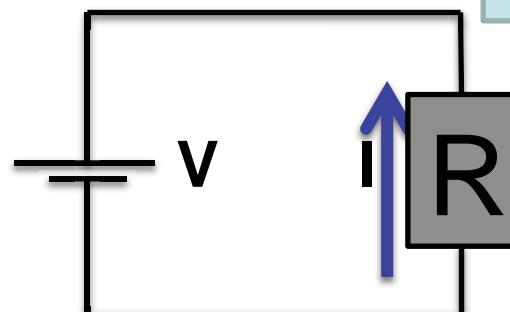
Dispersive current: Macroscopic non-equilibrium process



environment,
temperature T

$$P_\tau(\Delta S)$$

But: reverse processes
are not forbidden!



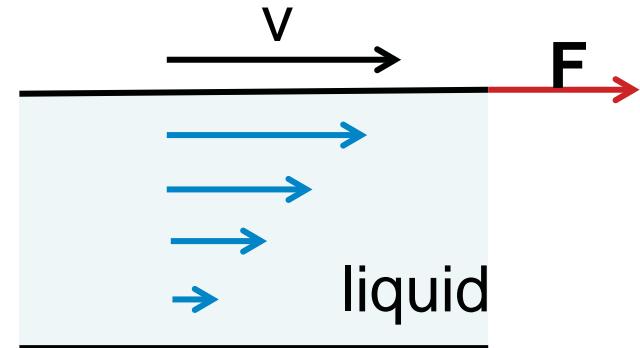
environment,
temperature T

$$P_\tau(-\Delta S)$$

Entropy is **fluctuating variable**, probability $P_\tau(\Delta S)$

Fluctuation theorem: quantitative statement about $P_\tau(\Delta S)$

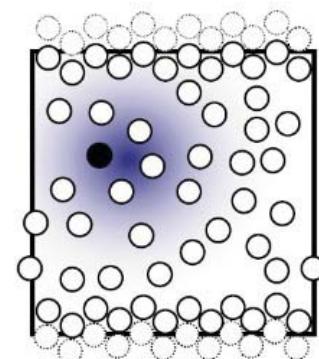
$$\frac{P_\tau(\Delta S)}{P_\tau(-\Delta S)} = \exp\left(\frac{\Delta S}{k_B}\right)$$



D.J. Evans, E.G.D. Cohen, G.P. Morriss, PRL 71, 2401 (1993).

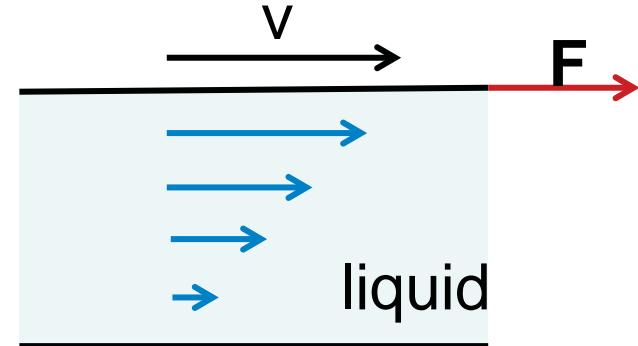
First experimental test: Latex bead moving in
a liquid

G.M. Wang et al., PRL 89, 050601 (2002).



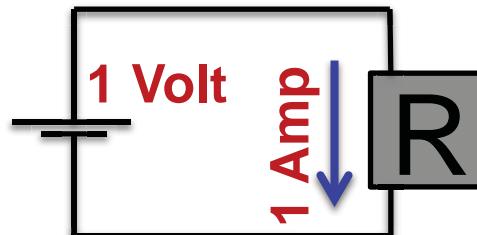
Fluctuation theorem: quantitative statement about $P_\tau(\Delta S)$

$$\frac{P_\tau(\Delta S)}{P_\tau(-\Delta S)} = \exp\left(\frac{\Delta S}{k_B}\right)$$



D.J. Evans, E.G.D. Cohen, G.P. Morriss, PRL 71, 2401 (1993).

Not relevant for macroscopic systems: $\Delta S < 0$ just does not occur



environment,
temperature T

$$\exp\left(\frac{\Delta S}{k_B}\right) = \exp\left(\frac{1V \cdot 1A \cdot 1s}{k_B \cdot 300K}\right) \approx 10^{(10^{20})}$$

Realization

A different system: Fluctuations
of the charge across a
mesoscopic conductor

$$\frac{P_\tau(n)}{P_\tau(-n)} = \exp\left(\frac{neV}{k_B T}\right)$$

Thermal equilibrium: $V = 0 \rightarrow P_\tau(n) = P_\tau(-n)$

High-bias regime: $eV \gg kT \rightarrow P_\tau(n) \gg P_\tau(-n)$

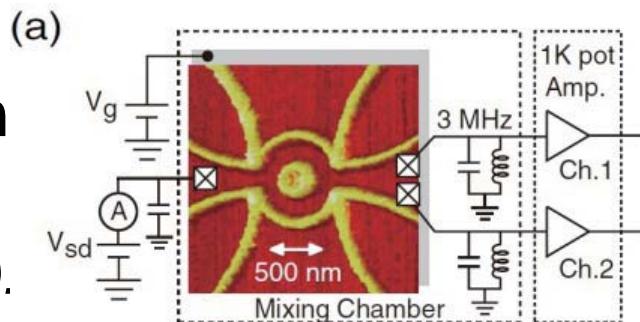
Realization

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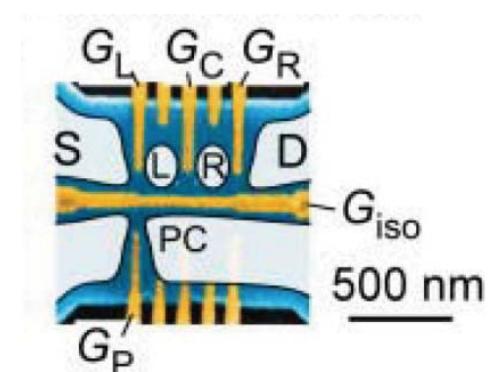
→ Low temperatures and **quantum coherence**

S. Nakamura *et al.*, PRL 104, 080602 (2010).



→ Observing a dissipative **current flow as individual electrons**

Y. Utsumi *et al.*, PRB 81, 125331 (2010).
T. Fujisawa *et al.*, Science 312, 1634 (2006).

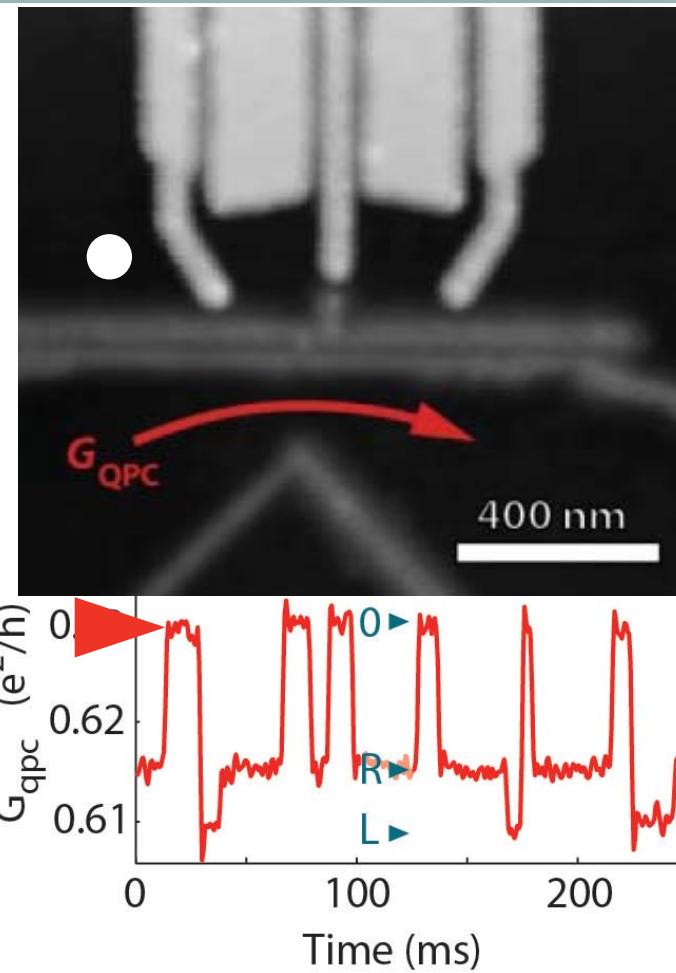


Microscopic approach

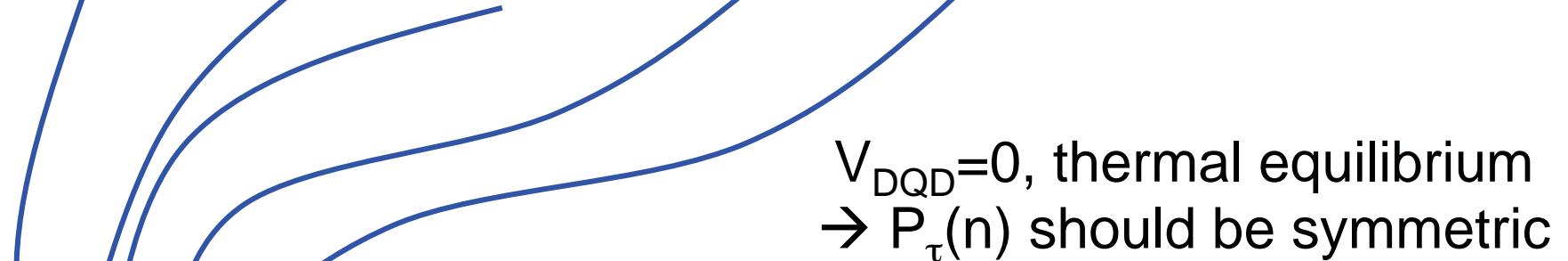
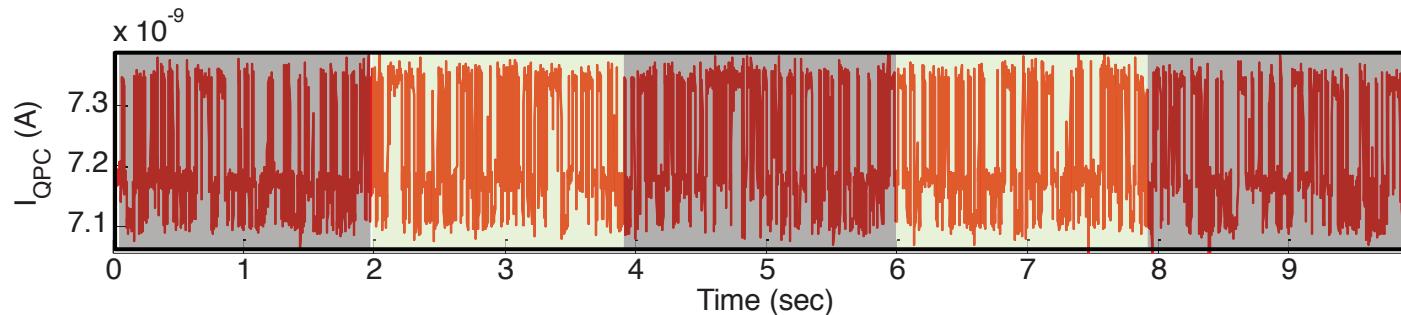
Microscopic: ability to measure extremely small currents, by
counting electrons

QPC sensor detects the
position of electrons inside
the structure

detect the number and
direction of electrons
passing the structure

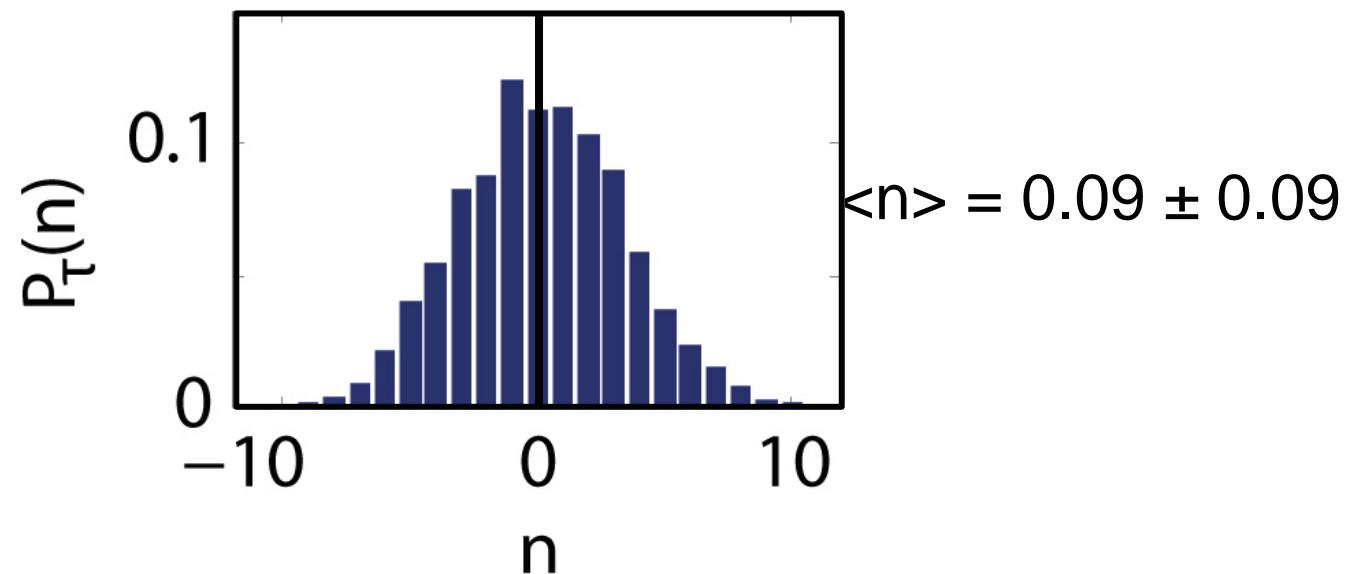


Counting electrons



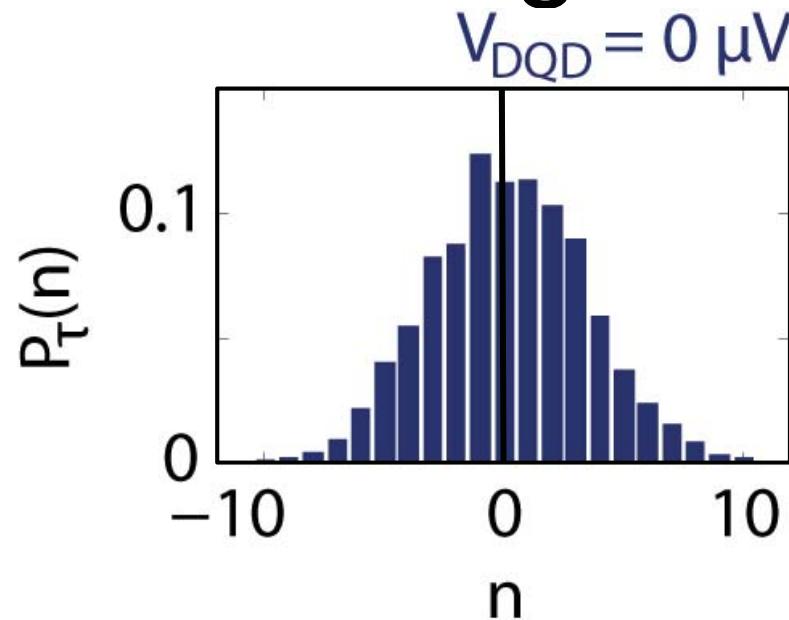
$V_{DQD}=0$, thermal equilibrium
→ $P_\tau(n)$ should be symmetric

3000 time bins,
length $\tau=2\text{sec}$



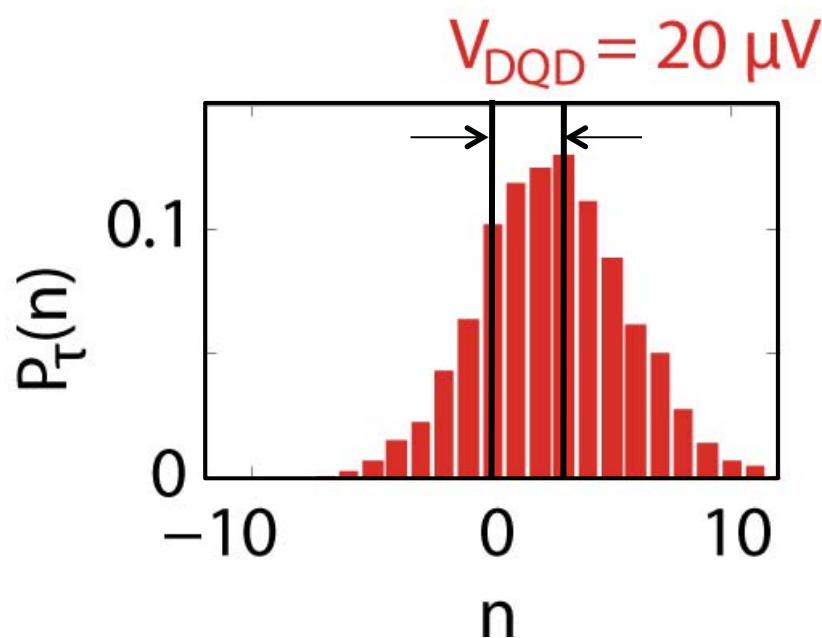
$$\langle n \rangle = 0.09 \pm 0.09$$

Counting electrons: finite bias



$V_{DQD} = 0$
→ no charge flow

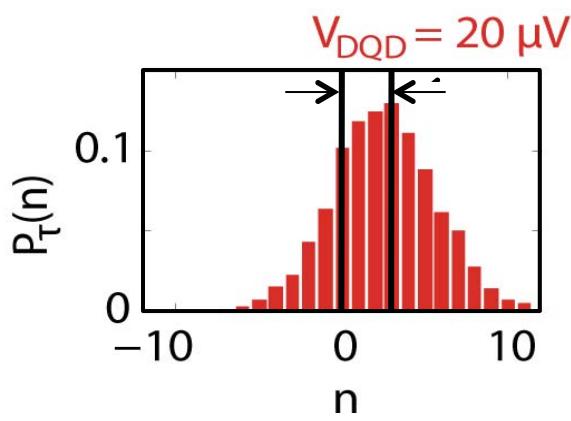
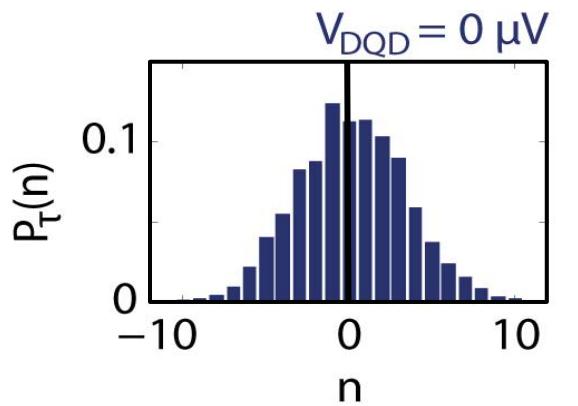
$$\langle n \rangle = 0.09 \pm 0.09$$



$V_{DQD} = 20 \mu V$
→ finite charge flow

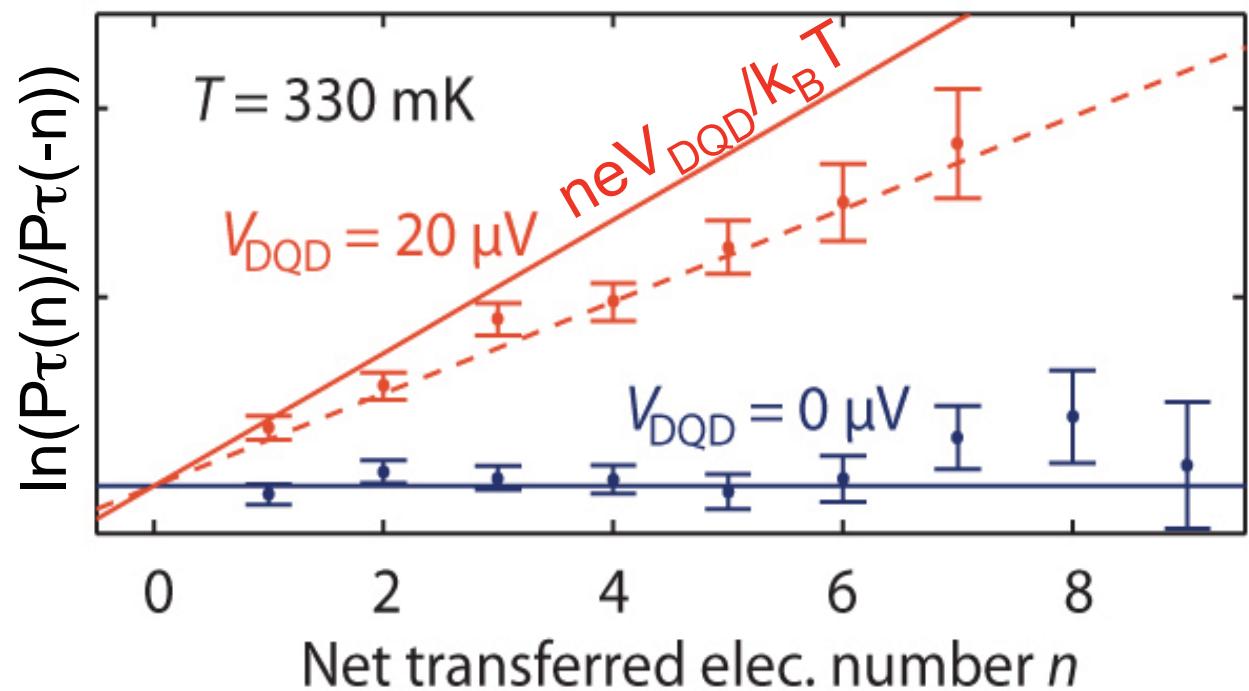
$$\langle n \rangle = 2.39 \pm 0.09$$

Counting electrons: finite bias



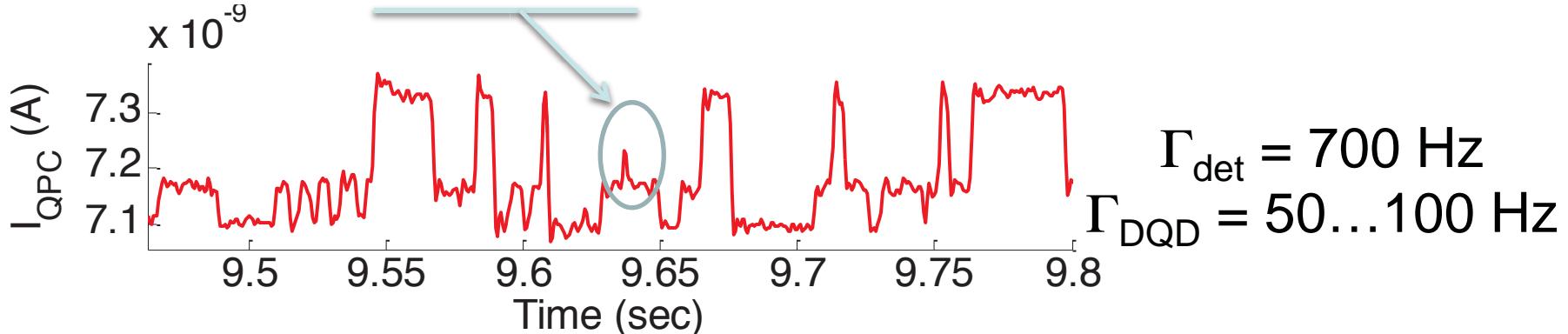
slope about 20%
smaller than
expected from
theory (solid line)

$$\frac{P_\tau(n)}{P_\tau(-n)} = \exp\left(\frac{neV}{k_B T}\right)$$



Counting electrons: finite bias

Detector can miss fast events due to limited bandwidth

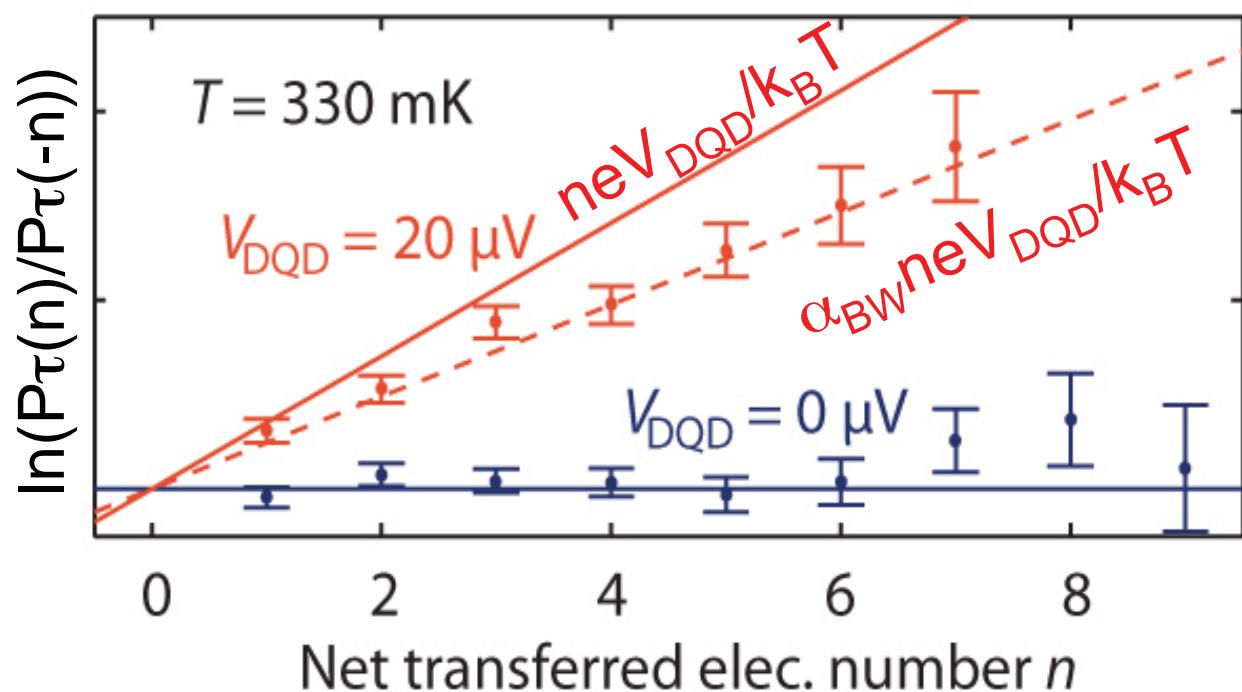


Theoretical modeling
(rate-equations):

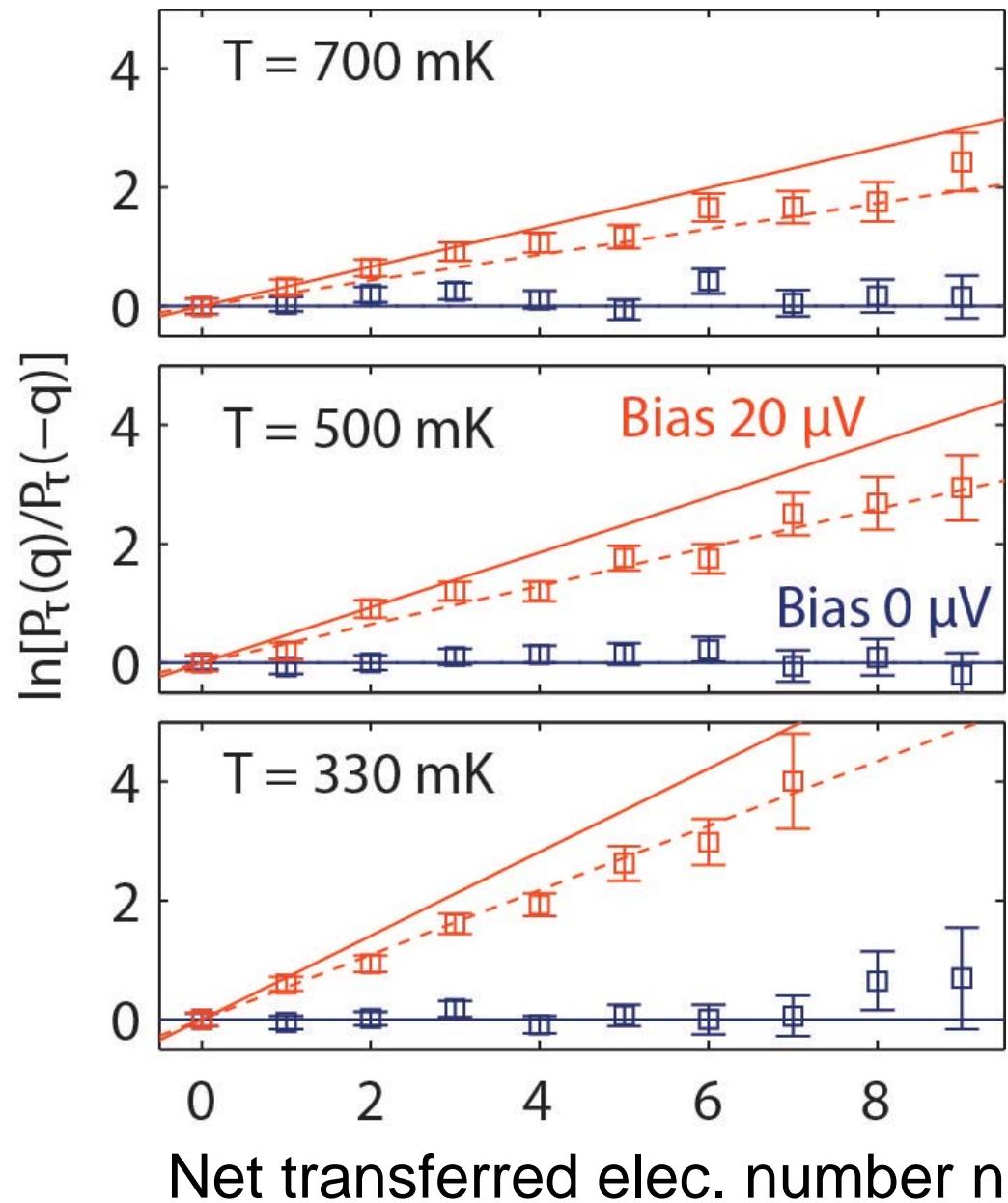
$$\alpha_{\text{BW}}$$

O. Naaman and J. Aumentado, PRL 96, 100201 (2006).

Y. Utsumi et al., (World Scientific, 2010), pp. 397-414



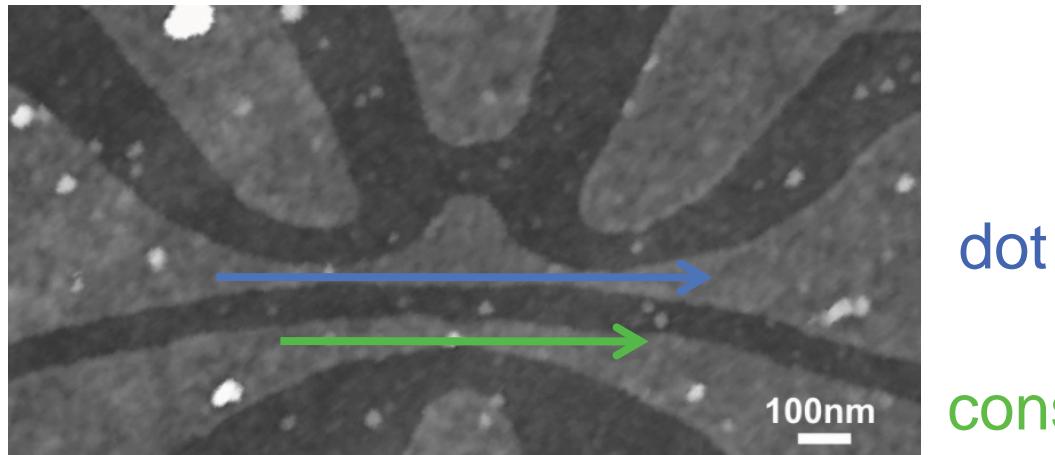
Counting electrons: finite bias



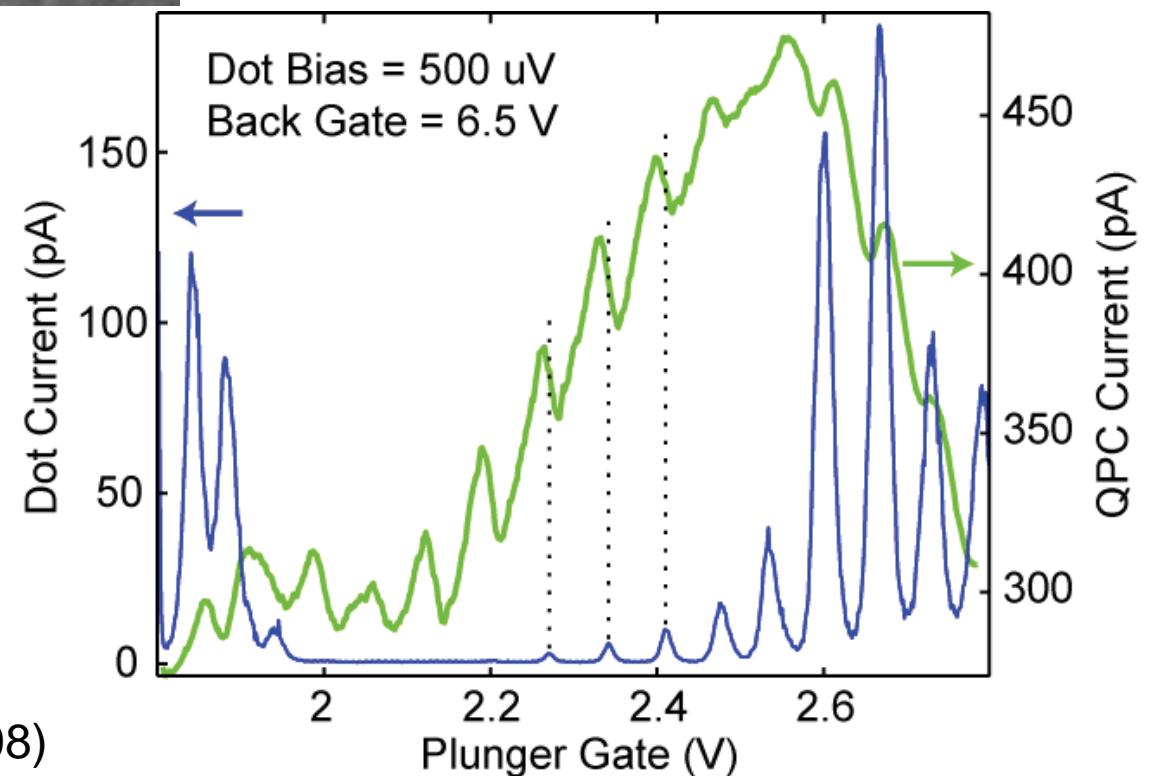
different
temperatures

$$\frac{P_\tau(n)}{P_\tau(-n)} = \exp\left(\frac{neV}{k_B T}\right)$$

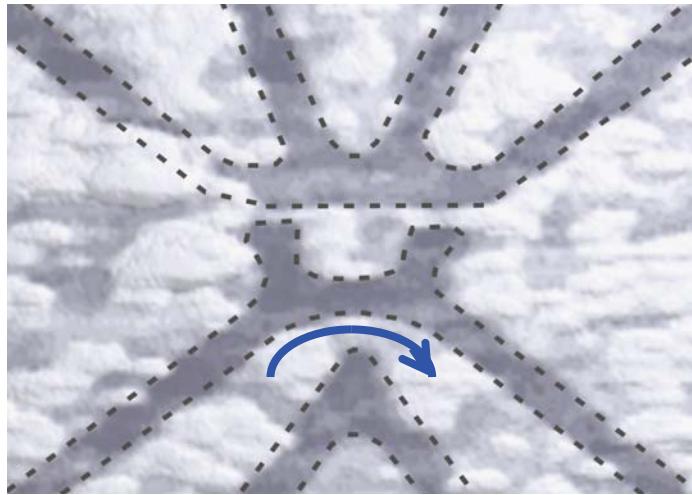
Graphene dot with charge detector



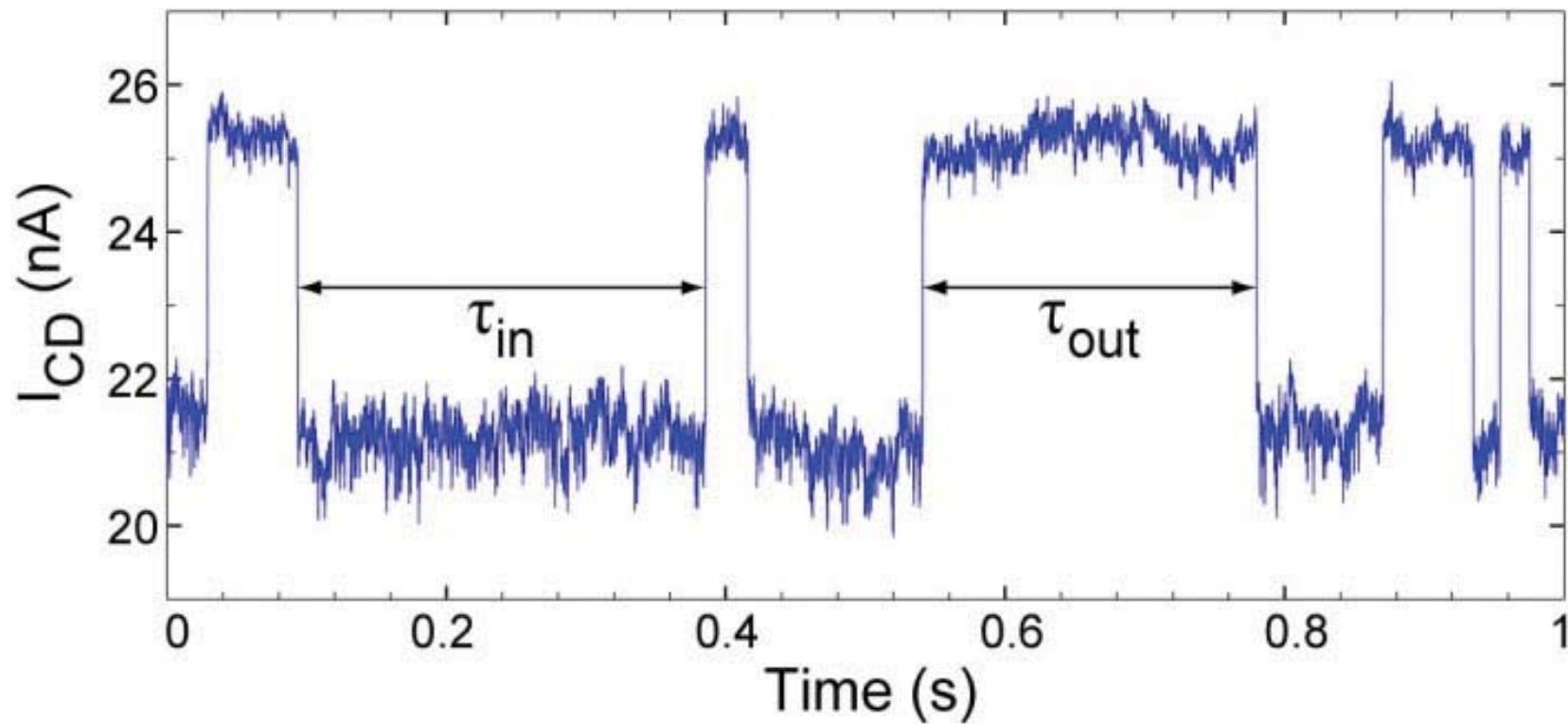
C. Stampfer,
S. Hellmüller,
J. Güttinger,
F. Molitor,
T. Ihn



Güttinger et al. APL 93, 212102 (2008)



Electron counting in graphene



J. Güttinger, C. Achille, C. Stampfer

Bruno Künig



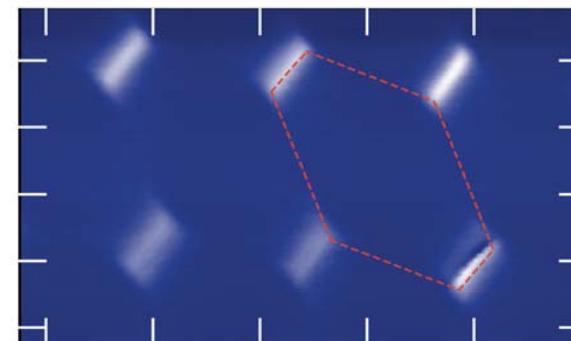
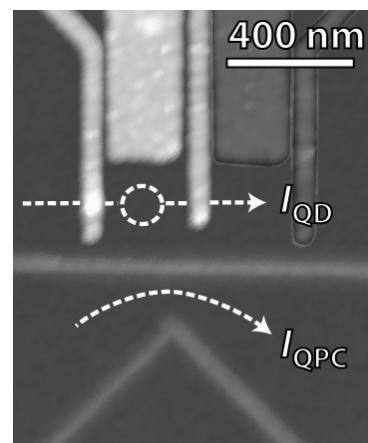
Thomas Ihn



Clemens
Rössler



Thank you



PRL 108, 046807 (2012)

PRX 2, 011001 (2012)

Samples: Christian Reichl, Werner Wegscheider
ETH Zurich

Theory: M. Marthaler (Karlsruhe), D.S. Golubev
(Karlsruhe), Y. Utsumi (Mie, Japan)
A. Blais (Sherbrooke)

Tobias Frey



Peter Leek



Andreas Wallraff

